NSN 5961-01-156-7910

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-156-7910 **Inclosure Material:** Glass **Overall Length:** 0.225 inches **Terminal Length:** 0.800 inches **Overall Diameter:** 0.140 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.2 working peak reverse voltage **Current Rating Per Characteristic:** 17.20 amperes forward current, average pascal **Power Rating Per Characteristic:** 500.0 watts small-signal input power, common-collector pascal **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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